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## **An update on measurements with Si detectors irradiated to extreme fluences**

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Silicon detectors were irradiated with with reactor neutrons up to very high fluences of  $3e17$  n/cm<sup>2</sup>. First results of measurements at these fluences were shown at the 32nd RD50 workshop. New charge collection measurements with Sr-90 source and new E-TCT measurements will be presented in this contribution.

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